2SD655

Rev.E Mar.-2016

蓝箭电子 BLUE ROCKET ELECTRONICS

DATA SHEET

/ Descriptions

TO-92 NPN Silicon NPN transistor in a TO-92 Plastic Package.

/ Features

Low frequency.

/ Applications

Low frequency power amplifier.

/ Equivalent Circuit

/ Pinning



PIN1 Base PIN 2 Collector PIN 3 Emitter

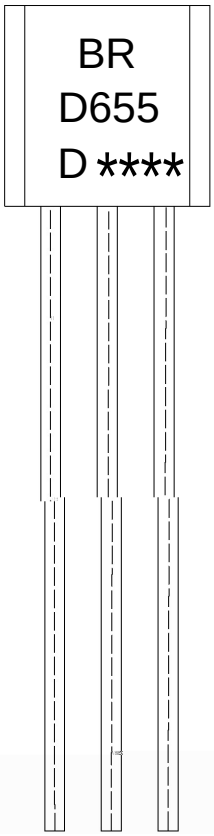
/ hFE Classifications & Marking

h_{FE} Classifications Symbol	D	E	F
h_{FE} Range	250~500	400~800	600~1200

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	30	V
Collector to Emitter Voltage	V_{CEO}	15	V
Emitter to Base Voltage	V_{EBO}	5.0	V
Collector Current - Continuous	I_C	700	mA
Collector Current – Continuous(Pulse)	I_{CP}	1.0	A
Collector Power Dissipation	P_C	500	mW

2SD655

/ Marking Instructions



BR:

D655

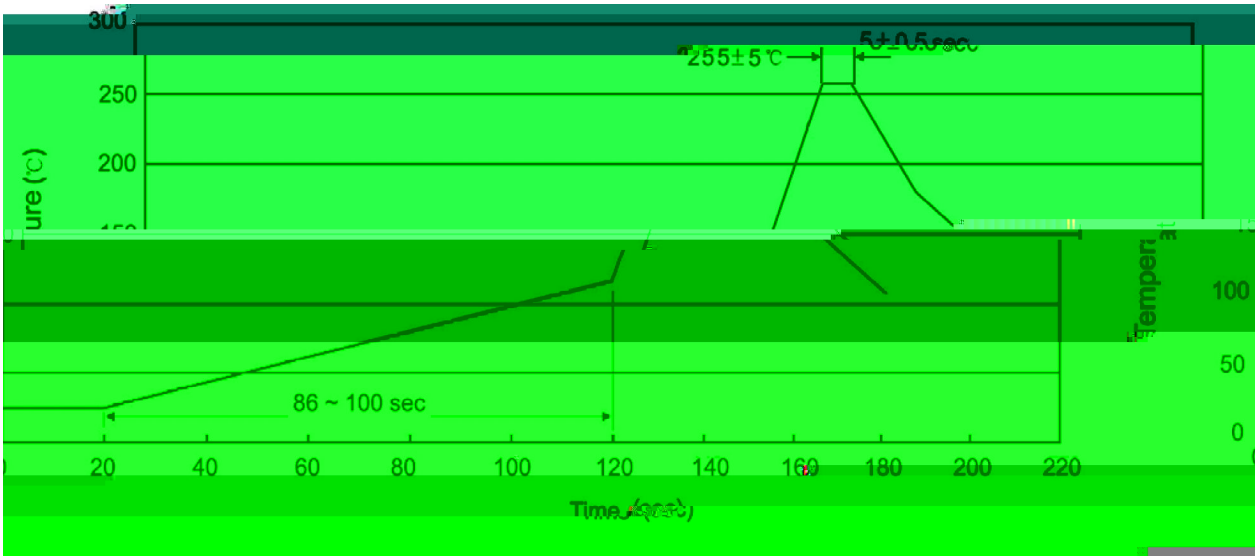
D: h_{FE}

****

Note:

BR:	Company Code.
D655:	Product Type.
D:	h_{FE} Classifications Symbol
****:	Lot No. Code,code change with Lot No.

( ) / Temperature Profile for Dip Soldering(Pb-Free)



Note:

1 25 150 60 90sec;
1.Preheating:25~150 , Time:60~90sec.

2 255±5 5±0.5sec;
2.Peak Temp.:255±5 , Duration:5±0.5sec.

3 2 10 /sec.
3. Cooling Speed: 2~10 /sec.

/ Resistance to Soldering Heat Test Conditions

270±5 10±1 sec. Temp:270±5 Time:10±1 sec

/ Packaging SPEC.

/ BULK

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm3)		
	Units/Bag 只/袋	Bags/Inner Box 袋/盒	Units/Inner Box 只/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Bag 袋	Inner Box 盒	Outer Box 箱
TO-92	1,000	10	10,000	5	50,000	135×190	237×172×102	560×245×195